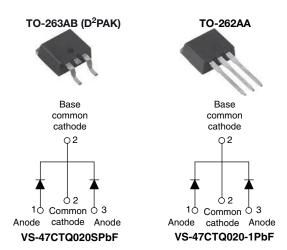


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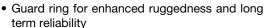
High Performance Schottky Rectifier, 2 x 20 A



| PRODUCT SUMMARY | |
|----------------------------------|---|
| Package | TO-263AB (D ² PAK), TO-262AA |
| I _{F(AV)} | 2 x 20 A |
| V_{R} | 20 V |
| V _F at I _F | 0.34 V |
| I _{RM} max. | 310 mA at 125 °C |
| T _J max. | 150 °C |
| Diode variation | Common cathode |
| E _{AS} | 18 |

FEATURES

- 150 °C T_J operation
- Center tap configuration
- Optimized for 3.3 V application
- Ultralow forward voltage drop
- · High frequency operation





- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

This center tap Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for 3.3 V output power supplies. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|--|-------------|-------|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | |
| I _{F(AV)} | Rectangular waveform | 40 | A | | |
| V _{RRM} | | 20 | V | | |
| I _{FSM} | t _p = 5 μs sine | 1000 | A | | |
| V _F | 20 A _{pk} , T _J = 125 °C | 0.34 | V | | |
| T _J | | -55 to +150 | °C | | |

| VOLTAGE RATINGS | | | | | |
|---|----------------|--------|----|---|--|
| PARAMETER SYMBOL TEST CONDITIONS VS-47CTQ020SPbF VS-47CTQ020-1PbF UNITS | | | | | |
| Maximum DC reverse voltage | V_{R} | 125 °C | 20 | V | |
| Maximum DC reverse voltage | v _R | 150 °C | 10 | V | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | |
|-----------------------------|----------------|--------------------|--|---|--------|-------|
| PARAMETER | | SYMBOL | TEST CONDITIONS | | VALUES | UNITS |
| Maximum average | per leg | | 50.0/ duty ovalo at T = 125.00 | rootongular wayoform | 20 | |
| forward current per dev | per device | I _{F(AV)} | 50 % duty cycle at T_C = 135 °C, rectangular waveform | | 40 | |
| Maximum peak one cycle | | | 5 μs sine or 3 μs rect. pulse | Following any rated load | 1000 | A |
| non-repetitive surge currer | nt per leg | I _{FSM} | 10 ms sine or 6 ms rect. pulse | condition and with rated V _{RRM} applied | 250 | |
| Non-repetitive avalanche | energy per leg | E _{AS} | $T_J = 25 ^{\circ}\text{C}, I_{AS} = 3 \text{A}, L = 3 \text{mH}$ | | 18 | mJ |
| Repetitive avalanche curre | ent per leg | I _{AR} | Current decaying linearly to zero Frequency limited by T _J maximu | | 3 | Α |



VS-47CTQ020SPbF, VS-47CTQ020-1PbF

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| ELECTRICAL SPECIFICATIONS | | | | | |
|---|--------------------------------|--|---------------------------------------|--------|--------------------|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS |
| | | 20 A | T _{.1} = 25 °C | 0.45 | |
| | | 40 A | 1J=25 C | 0.51 | |
| Maximum famuard valtage drep per les | V (1) | 20 A | T 105 °C | 0.34 | V |
| Maximum forward voltage drop per leg | V _{FM} ⁽¹⁾ | 40 A | - T _J = 125 °C | 0.44 | ľ |
| | | 20 A | T _ 150 °C | 0.31 | 0.31 0.42 60 |
| | | 40 A | $T_J = 150 ^{\circ}\text{C}$ | 0.42 | |
| | | T 105 °C | V _R = 5 V | 60 | 60 45 |
| | I _{RM} ⁽¹⁾ | T _J = 125 °C | V _R = 3.3 V | 45 | |
| Maximum reverse leakage current per leg | | T _J = 150 °C | V _R = 10 V | 306 | mA |
| canoni por log | | T _J = 25 °C | V Datad V | 3 | |
| | | T _J = 125 °C | V _R = Rated V _R | 310 | |
| Threshold voltage | V _{F(TO)} | $T_J = T_J$ maximum | | 0.188 | V |
| Forward slope resistance | r _t | | | 5.9 | mΩ |
| Maximum junction capacitance per leg | C _T | V _R = 5 V _{DC} (test signal rang | ge 100 kHz to 1 MHz), 25 °C | 3000 | pF |
| Typical series inductance per leg | L _S | Measured lead to lead 5 m | m from package body | 5.5 | nH |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 000 | V/µs |

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

| THERMAL - MECHA | NICAL SP | ECIFICAT | IONS | | |
|--|----------------------------------|-----------------------------------|--------------------------------------|-------------|------------|
| PARAMETER | ER SYMBOL TEST CONDITIONS VALUES | | UNITS | | |
| Maximum junction and stora temperature range | ge | T _J , T _{Stg} | | -55 to +150 | °C |
| Maximum thermal resistance, junction to case per leg | | В | DC operation | 1.5 | |
| Maximum thermal resistance, junction to case per package | | - R _{thJC} | DC operation | 0.75 | °C/W |
| Typical thermal resistance, case to heatsink | | | Mounting surface, smooth and greased | 0.50 | |
| Approximate weight | | | | 2 | g |
| Approximate weight | | | | 0.07 | oz. |
| Maunting toyour | minimum | | | 6 (5) | kgf · cm |
| Mounting torque | maximum | | | 12 (10) | (lbf · in) |
| Maybing daying | | | Case style TO-263AB (D2PAK) | 47CTQ020S | |
| Marking device | | | Case style TO-262AA | 47CTQ0 | 20-1 |

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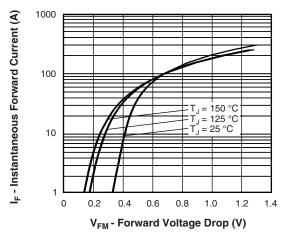


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

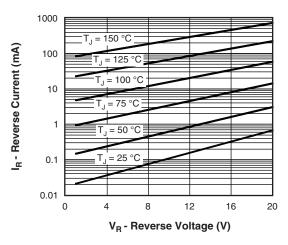


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

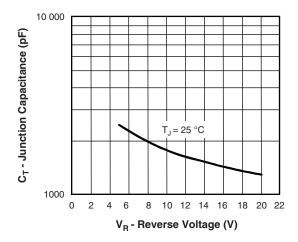


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

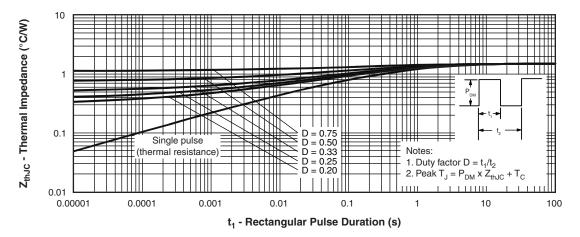


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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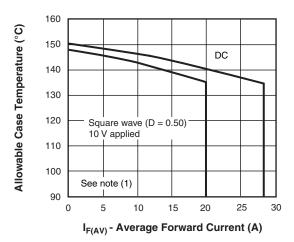


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

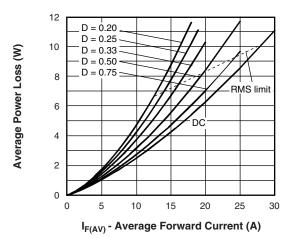


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

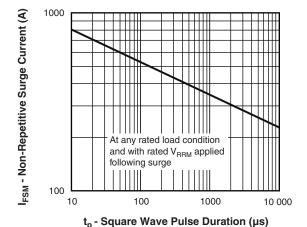


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

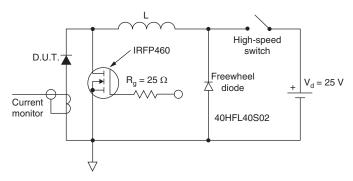


Fig. 8 - Unclamped Inductive Test Circuit

Note

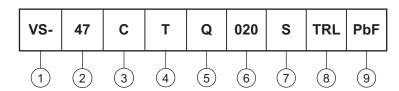
 $^{(1)}$ Formula used: $T_C = T_J$ - (Pd + Pd_{REV}) x R_{thJC}; Pd = Forward power loss = $I_{F(AV)}$ x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 10 V

VS-47CTQ020SPbF, VS-47CTQ020-1PbF

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- Current rating (40 A)
- 3 Circuit configuration: C = common cathode
- **4** T = TO-220
- 5 Schottky "Q" series
- 6 Voltage rating (020 = 20 V)
- 7 • S = D²PAK
 - -1 = TO-262
- None = tube (50 pieces)
 - TRL = tape and reel (left oriented for D²PAK only)
 - TRR = tape and reel (right oriented for D²PAK only)
- 9 PbF = lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | |
|--------------------------------|-------------------|------------------------|------------------------------------|--|--|
| PREFERRED P/N | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | |
| VS-42CTQ020SPBF | 50 | 1000 | Antistatic plastic tubes | | |
| VS-42CTQ020STRRPBF | 800 | 800 | 13" diameter plastic tape and reel | | |
| VS-42CTQ020STRLPBF | 800 | 800 | 13" diameter plastic tape and reel | | |
| VS-42CTQ020-1PBF | 50 | 1000 | Antistatic plastic tubes | | |

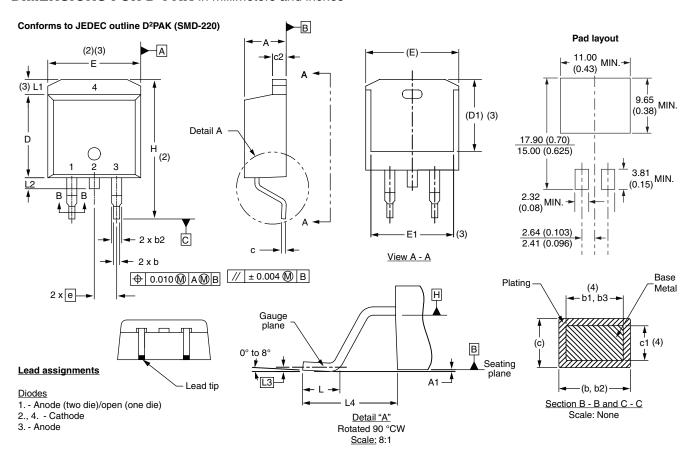
| LINKS TO RELATED DOCUMENTS | | | | |
|---|----------|--------------------------|--|--|
| Dimensions TO-263AB (D ² PAK) <u>www.vishay.com/doc?95046</u> | | | | |
| Dimensions | TO-262AA | www.vishay.com/doc?95419 | | |
| Part marking information | | www.vishay.com/doc?95008 | | |
| Packaging information | | www.vishay.com/doc?95032 | | |



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



| 0)//// | MILLIM | IETERS | INC | | |
|--------|--------|--------|-------|-------|-------|
| SYMBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |

| SYMBOL | MILLIM | ETERS | INC | HES | NOTES |
|----------|----------|-------|-----------|-------|-------|
| STIVIBOL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.100 BSC | | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | - | 1.65 | - | 0.066 | 3 |
| L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| L3 | 0.25 BSC | | 0.010 | BSC | |
| L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

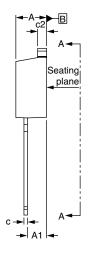
(7) Outline conforms to JEDEC outline TO-263AB

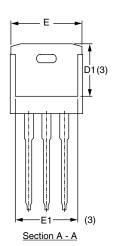
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments

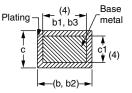


<u>Diodes</u>

-3 x b2 --3 x b

> 1. - Anode (two die)/open (one die) 2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

| SYMBOL | MILLIMETERS | | INC | CHES | NOTES |
|--------|-------------|-------|-------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | NOTES |
| Α | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.10 | 0 BSC | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | |
| L1 | - | 1.65 | - | 0.065 | 3 |
| L2 | 3.56 | 3.71 | 0.140 | 0.146 | |

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



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